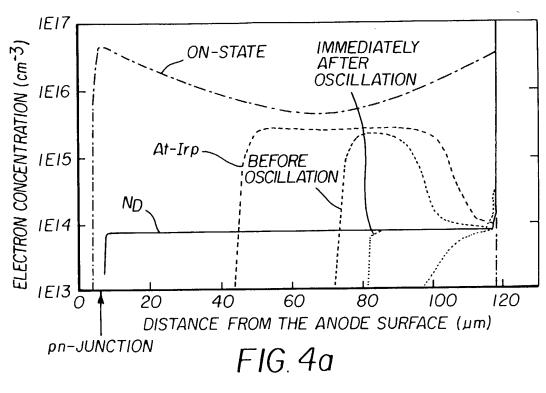
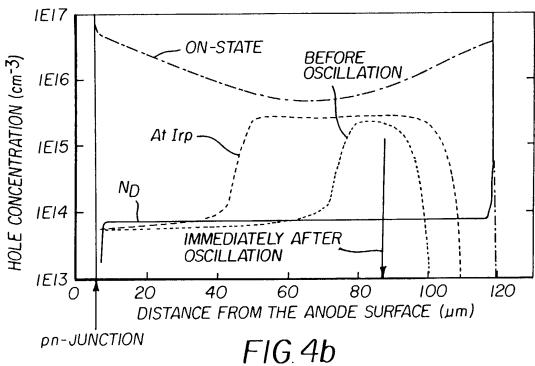
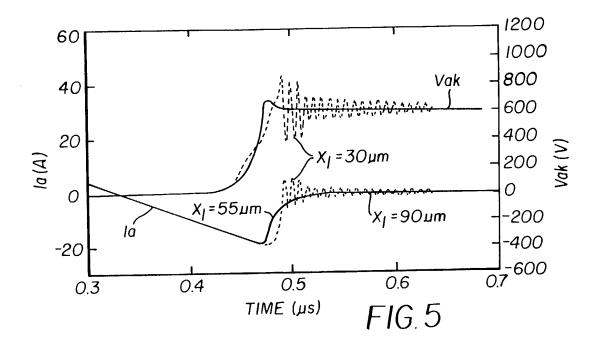


US Serial No 10/083,673 3/20







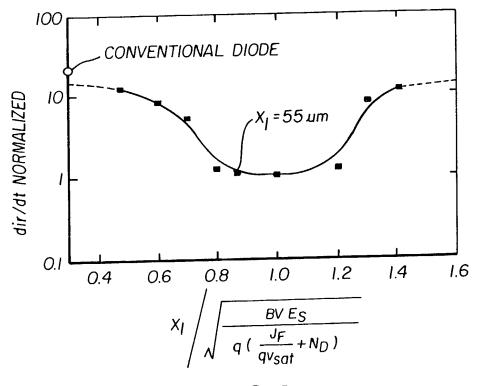
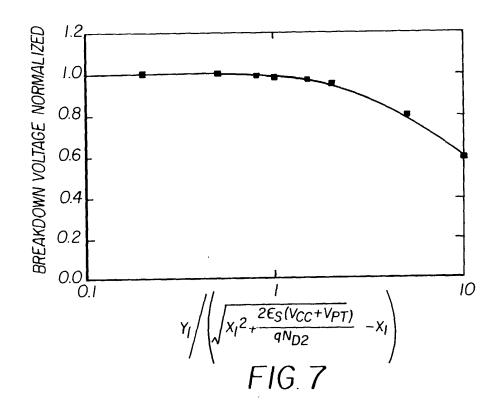
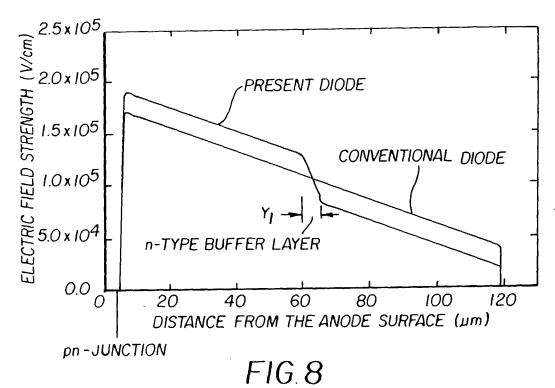
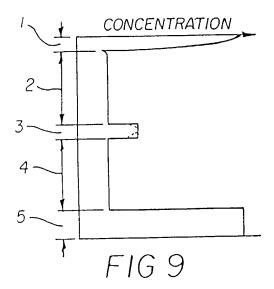
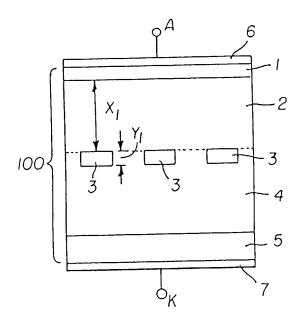


FIG.6

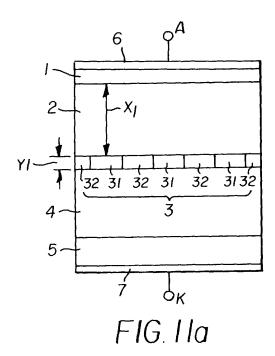


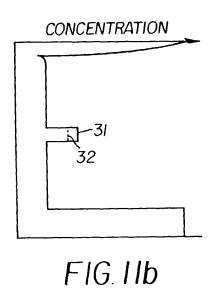


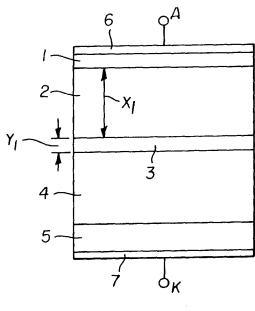




F1G.10









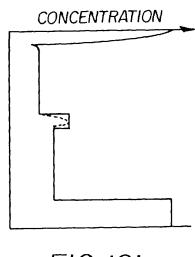
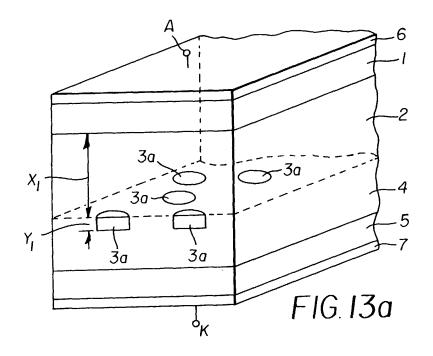
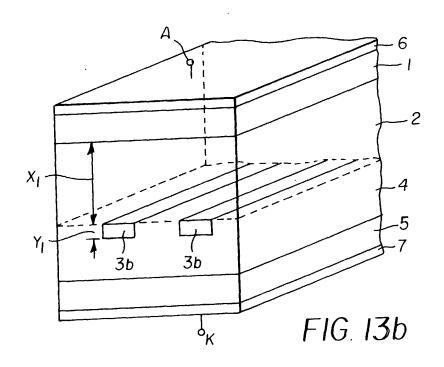


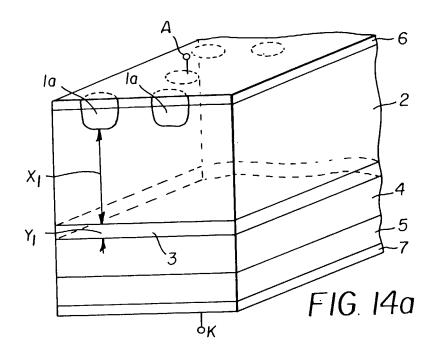
FIG. 12b

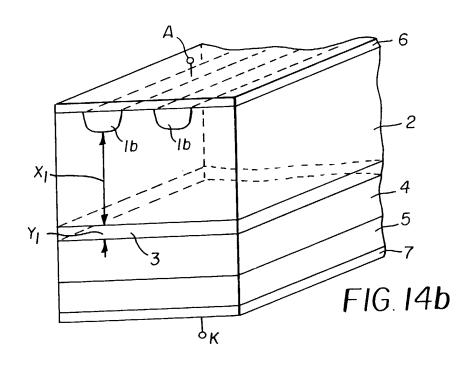
Semiconductor Device and Method of Manufacturing the Same
Nemoto et al
US Serial No. 10/083,673
8/20

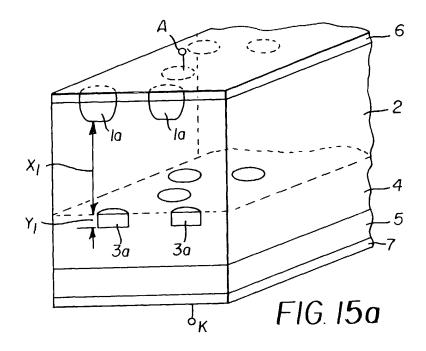


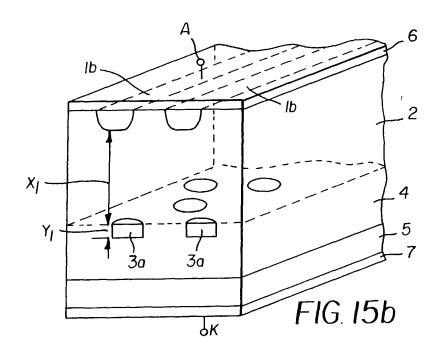


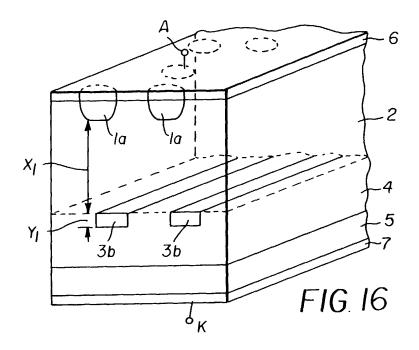
Semiconductor Device and Method of Manufacturing the Same Nemoto et al US Serial No 10/083,673 9/20

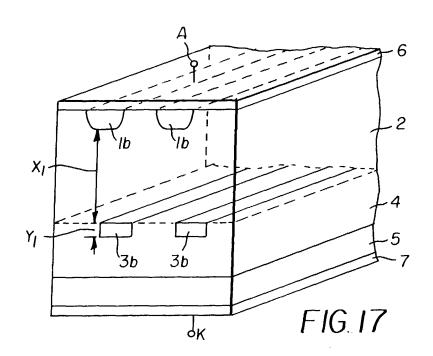












Semiconductor Device and Method of Manufacturing the Same

Nemoto et al

US Serial No. 10/083,673

12/20

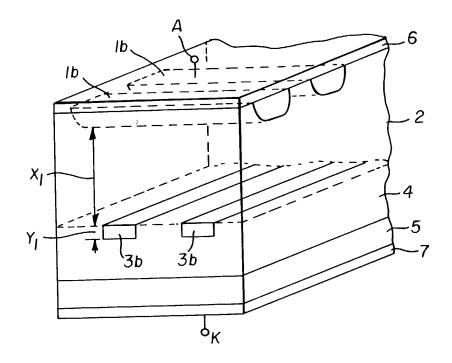
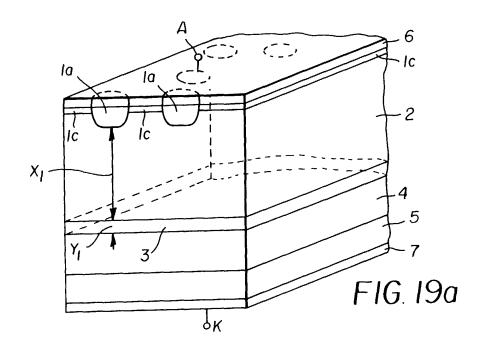
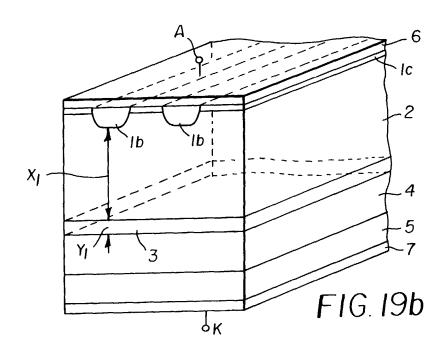
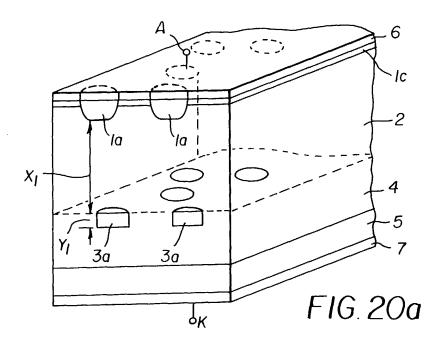
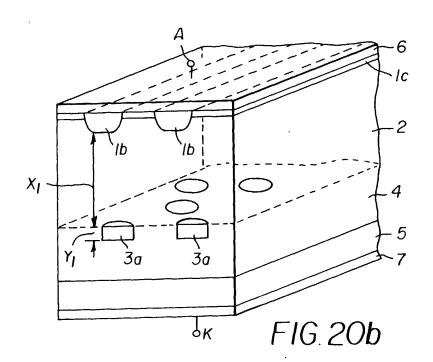


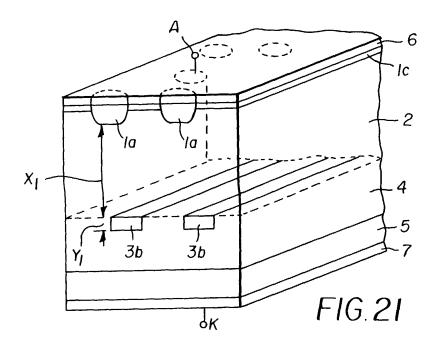
FIG. 18

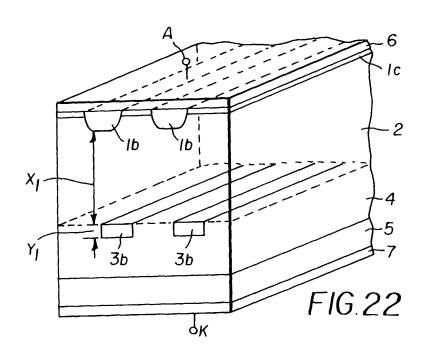




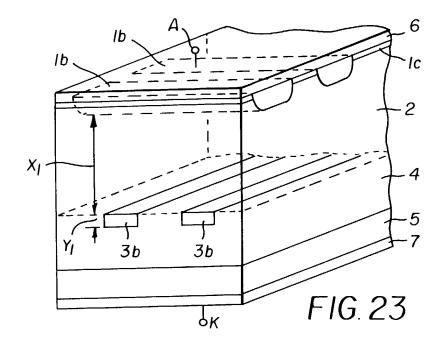


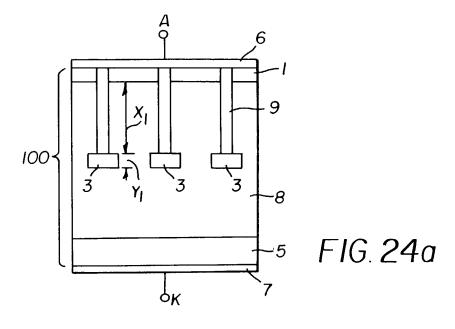






Semiconductor Device and Method of Manufacturing the Same
Nemoto et al.
US Serial No. 10/083,673
16/20





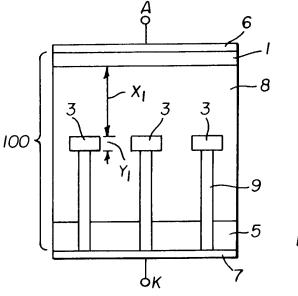
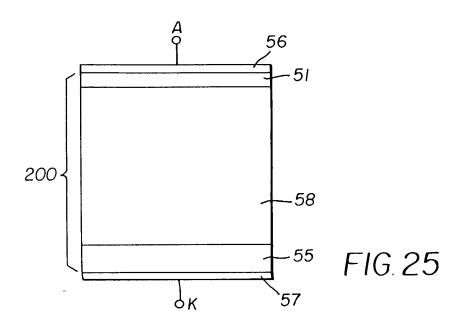
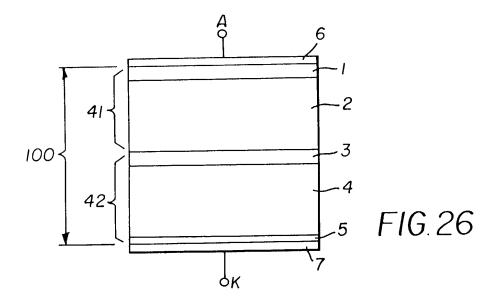
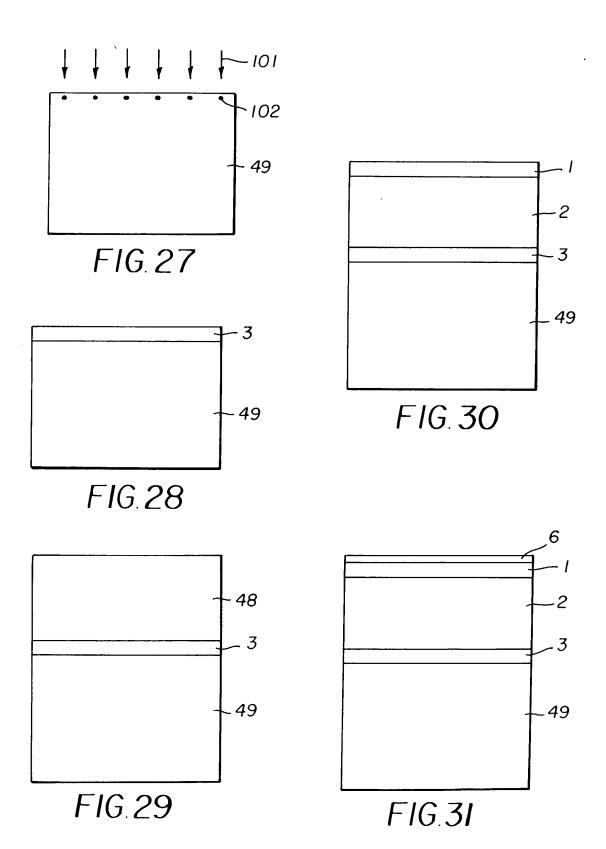


FIG. 24b







US Serial No. · 10/083,673 20/20

